

SEMICONDUCTOR TM

## KSC2690/2690A

# **Audio Frequency** High Frequency Power Amplifier Complement to KSA1220/KSA1220A



## NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol                           | Parameter                                    | Value      | Units |  |
|----------------------------------|--|------------|-------|--|
| V <sub>CBO</sub>                 | Collector-Base Voltage                       |            |       |  |
|                                  | : KSC2690                                    | 120        | V     |  |
|                                  | : KSC2690A                                   | 160        | V     |  |
| V <sub>CEO</sub>                 | Collector- Emitter Voltage                   |            |       |  |
| 020                              | : KSC2690                                    | 120        | V     |  |
|                                  | : KSC2690A                                   | 160        | V     |  |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                         | 5          | V     |  |
| I <sub>C</sub>                   | Collector Current (DC)                       | 1.2        | А     |  |
| I <sub>CP</sub>                  | *Collector Current (Pulse)                   | 2.5        | А     |  |
| I <sub>B</sub>                   | Base Current(DC)                             | 0.3        | А     |  |
|                                  | Collector Dissipation (T <sub>a</sub> =25°C) | 1.2        | W     |  |
| P <sub>C</sub><br>P <sub>C</sub> | Collector Dissipation (T <sub>C</sub> =25°C) | 20         | W     |  |
| ТJ                               | Junction Temperature                         | 150        | °C    |  |
| T <sub>STG</sub>                 | Storage Temperature                          | - 55 ~ 150 | °C    |  |

### Electrical Characteristics $T_{C}=25^{\circ}C$ unless otherwise noted

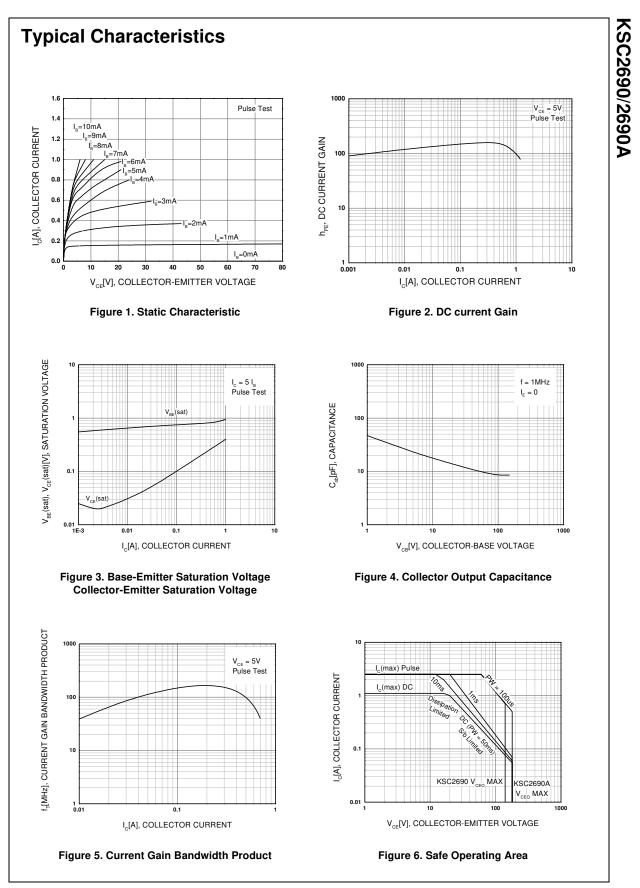
| Symbol                | Parameter                              | Test Condition                                    |    | Тур. | Max. | Units |  |
|-----------------------|--|---|----|------|------|-------|--|
| I <sub>CBO</sub>      | Collector Cut-off Current              | V <sub>CB</sub> = 120V, I <sub>E</sub> = 0        |    |      | 1    | μA    |  |
| I <sub>EBO</sub>      | Emitter Cut-off Current                | V <sub>EB</sub> = 3V, I <sub>C</sub> = 0          |    |      | 1    | μA    |  |
| h <sub>FE1</sub>      | * DC Current Gain                      | $V_{CE} = 5V, I_{C} = 5mA$                        | 35 | 105  |      |       |  |
| h <sub>FE2</sub>      |  | $V_{CE} = 5V, I_{C} = 0.3A$                       | 60 | 140  | 320  |       |  |
| V <sub>CE</sub> (sat) | * Collector-Emitter Saturation Voltage | I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A        |    | 0.4  | 0.7  | V     |  |
| V <sub>BE</sub> (sat) | * Base-Emitter Saturation Voltage      | I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A        |    | 1    | 1.3  | V     |  |
| f <sub>T</sub>        | Current Gain Bandwidth Product         | V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.2A       |    | 155  |      | MHz   |  |
| C <sub>ob</sub>       | Output Capacitance                     | V <sub>CB</sub> =10V, I <sub>E</sub> =0, f = 1MHz |    | 19   |      | pF    |  |

\* Pulse Test: PW≤350µs, Duty Cycle≤2% Pulsed

### h<sub>FE</sub> Classificntion

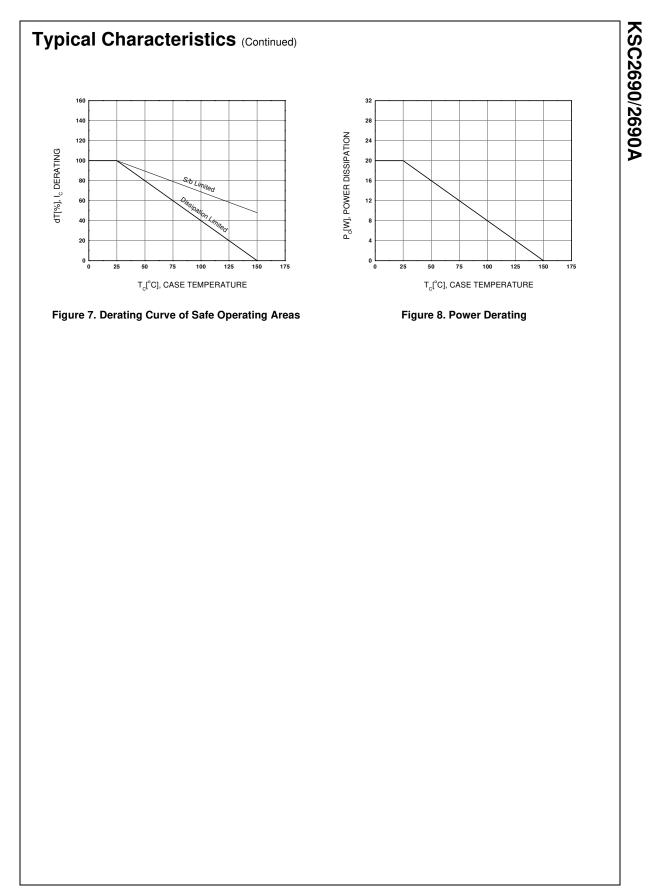
| Classification   | R        | 0         | Y         |  |
|------------------|----------|-----------|-----------|--|
| h <sub>FE2</sub> | 60 ~ 120 | 100 ~ 200 | 160 ~ 320 |  |

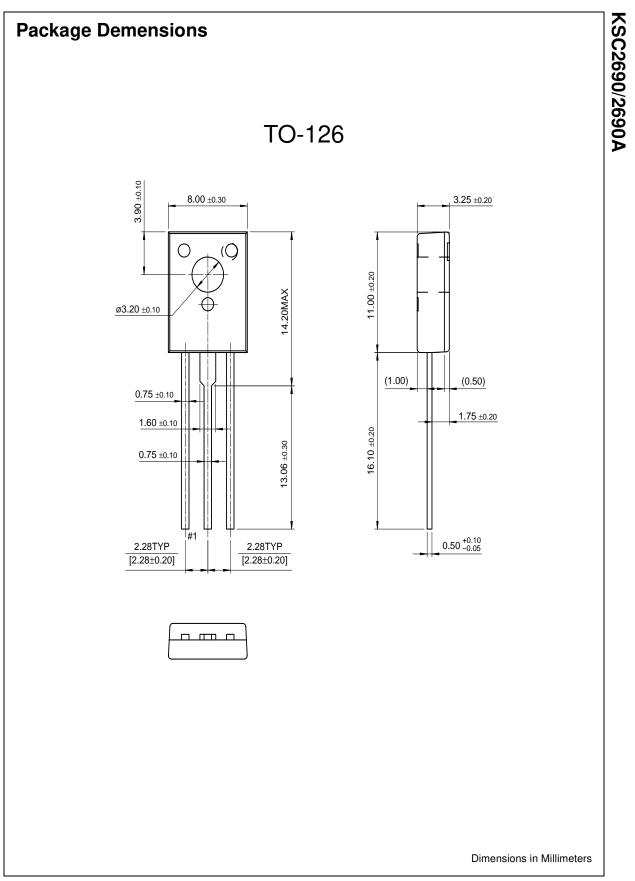
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|--------------------------|---------------------------|---|
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#### Features

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Product status/pricing/packaging

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| Product    | Product status     | Pb-free Status     | Pricing* | Package type  | Leads | Packing method | Package Marking Convention**  |  |
|------------|--------------------|--------------------|----------|---------------|-------|----------------|---|--|
| KSC2690YST | FU Full Production | Full<br>Production | \$0.194  | <u>TO-126</u> | 3     | RAIL           | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>3</b> (3-Digit Date Code)<br>Line 3: C2690A-Y |  |

\* Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product KSC2690 is available. Click here for more information.

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#### **Qualification Support**

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